



HER2001G thru HER2007G

Glass Passivated High Efficient Rectifiers
Reverse Voltage 50 to 1000 Volts Forward Current 2.0 Amperes

Features

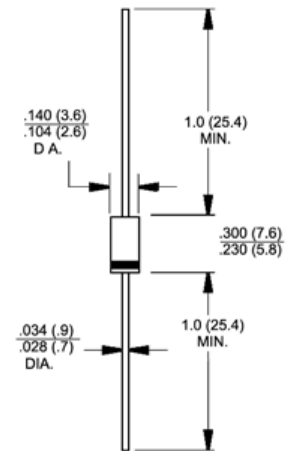
- ◆ Glass passivated chip
- ◆ Ultra fast switching for high efficiency
- ◆ Low reverse leakage current
- ◆ Low forward voltage drop
- ◆ High current capability
- ◆ Easily cleaned with Freon, Alcohol, Chlorothene and similar solvents
- ◆ Plastic material has UL flammability classification 94V-0



DO-204AC (DO-15)

Mechanical Data

- ◆ Case : JEDEC DO-204AC(DO-15) molded plastic
- ◆ Polarity : Color band denotes cathode
- ◆ Weight : 0.014 ounce, 0.395 gram
- ◆ Mounting position : Any



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Parameter	Symbols	HER 2001G	HER 2002G	HER 2003G	HER 2004G	HER 2005G	HER 2006G	HER 2007G	Units	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts	
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	Volts	
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	Volts	
Maximum average forward rectified current @ $T_A=55^\circ\text{C}$	$I_{(AV)}$	2.0							Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	60.0							Amps	
Maximum forward voltage at 2.0A DC	V_F	1.0		1.3		1.7			Volts	
Maximum DC reverse current @ $T_J=25^\circ\text{C}$ at rated DC blocking voltage @ $T_J=100^\circ\text{C}$	I_R	5.0				100				μA
Maximum reverse recovery time (Note 1)	t_{rr}	50				75				nS
Typical junction capacitance (Note 2)	C_j	30				15				pF
Typical thermal resistance (Note 3)	$R_{\theta JA}$	25							$^\circ\text{C/W}$	
Operating junction temperature range	T_J	-55 to +150							$^\circ\text{C}$	
Storage temperature range	T_{STG}	-55 to +150							$^\circ\text{C}$	

- Notes:**
1. Test condition of T_r : $I_F=0.5A, I_R=1.0A, I_{RR}=0.25A$.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 3. Thermal Resistance Junction to Ambient.

RATINGS AND CHARACTERISTIC CURVES

FIG.1 - FORWARD CURRENT DERATING CURVE

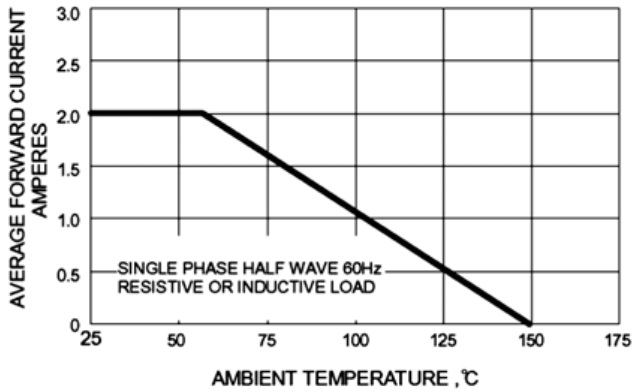


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

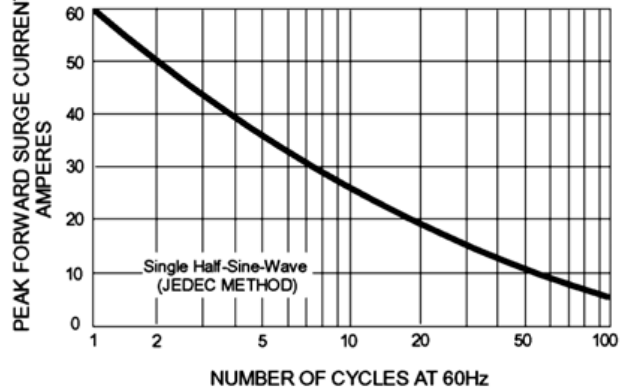


FIG.3 - TYPICAL JUNCTION CAPACITANCE

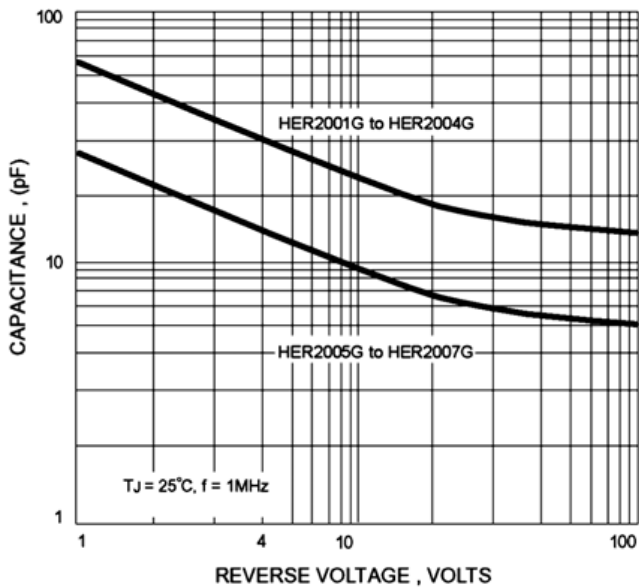


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

